



# SANYO Semiconductors

## DATA SHEET

# LA7795T — Monolithic Linear IC

## AGC Amplifier with Step Gain Control

### Overview

The LA7795T bipolar monolithic IC is an AGC amplifier with driver amplifier for analog-to-digital converters. It is ideally suited for use with receiver systems that receive QPSK and/or QAM data transmissions.

### Functions

- IF AGC control
- IF AGC amplifier
- IF step gain controlled amplifier
- Driver amplifier

### Applications

- Digital CATV
- Cable modem receivers
- IP Telephony receivers

### Specifications

#### Absolute Maximum Ratings at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Supply Voltage	V <sub>CC</sub> max	Pin 1	7.0	V
Circuit Voltages	V max	Pin 4, Pin 5	V <sub>CC</sub> op	V
Circuit Current	I <sub>6</sub> I <sub>7</sub>	Pin 6 sink current Pin 7 sink current	2 2	mA
Allowable Power Dissipation	Pd max	Ta ≤ 85°C	190*	mW
Operating Temperature	Topr		-20 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C

\*Mounted on PCB (paper phenol 20.0 × 10.0 × 0.8 t mm)

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**SANYO Semiconductor Co., Ltd.**

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# LA7795T

## Recommended Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended Supply Voltage	$V_{CC}$	Pin 1	5.0	V
Operating Supply Voltage Range	$V_{CC\ op}$	Pin 1	4.5 to 5.5	V

## Electrical Characteristics

### AC Characteristics at $T_a = 25^\circ\text{C}$ , $V_{CC} = 5.0\text{ V}$

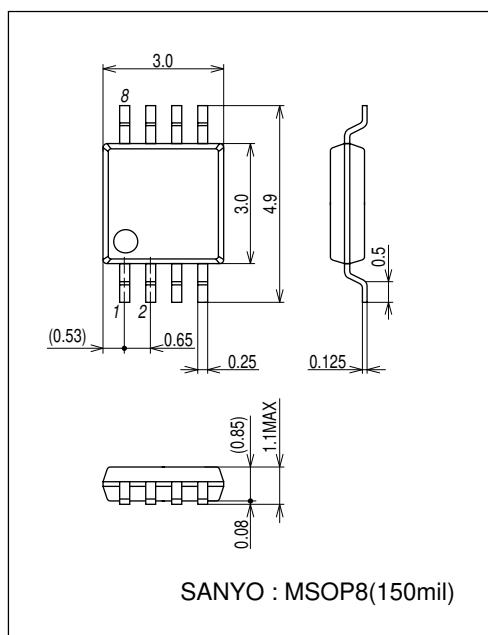
Parameter	Symbol	Pin No.	Conditions	Ratings			Unit
				min	typ	max	
Circuit Current	$I_{total}$	1	No Signal	*1	18	24	30 mA
IF Input Frequency Range	$f(\text{in})$	2, 3	$f_c : -3\text{ dB}$	*1	30	-	100 MHz
Noise Figure	NF	6, 7	$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : V_{CC}$	*2	-	5 dB
			$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : \text{GND}$	*2	-	5 dB
			$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : \text{OPEN}$	*2	-	8 dB
Intermodulation	IM3	6/2, 3 7/2, 3	$f_1 = 44\text{ MHz}, f_2 = 45\text{ MHz}$ $\text{Input} = 90\text{ dB}\mu/\text{Tone}, \text{Output} = 104\text{ dB}\mu/\text{Tone}$	*1	50	-	- dBc
Total Amplifier Gain	$G_{(\text{AGC}1)}$	6/2, 3 7/2, 3	$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : V_{CC}$	*1	57.5	60 dB
	$G_{(\text{AGC}2)}$		$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : \text{GND}$	*1	47.5	50 dB
	$G_{(\text{AGC}3)}$		$V_4 = 3.0\text{ V}, f = 45\text{ MHz}$	$\text{Pin } 5 : \text{OPEN}$	*1	33.5	36 dB
AGC Range 1	GR1	6/2, 3 7/2, 3	IF Output Level $< \pm 1\text{ dB}, f = 45\text{ MHz}$	*1	40	-	- dB
IF Output Level	$V_O(\text{IF})$	6, 7	Output Level, $f = 45\text{ MHz}$	*1	-	1.0	- V <sub>p-p</sub>
AGC Control Max. Voltage	$V_{4H}$	4	Gain Max.	*1	2.5	-	3.3 V
AGC Control Min. Voltage	$V_{4L}$	4	Gain Min.	*1	0	-	0.5 V
Input impedance	$Z_{in}$	2, 3	$V_4 = 0\text{ V}, f = 45\text{ MHz}$	*3	-	$1 // 4.9$	- k $\Omega$ // pF

Note) \*1 : Measurement circuit 1, \*2 : Measurement circuit 2, \*3 : Measurement circuit 3

## Package Dimensions

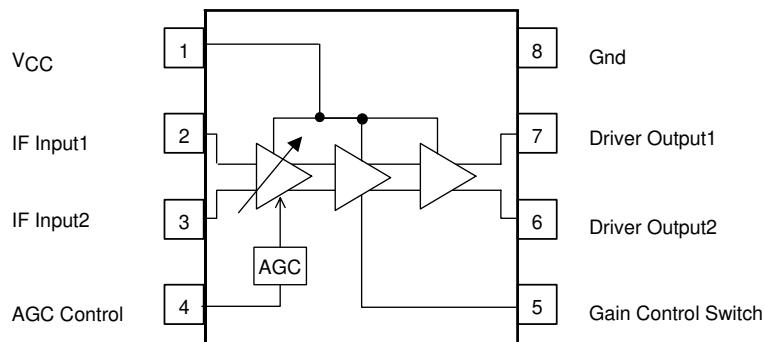
unit : mm (typ)

3245B



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## Block Diagram

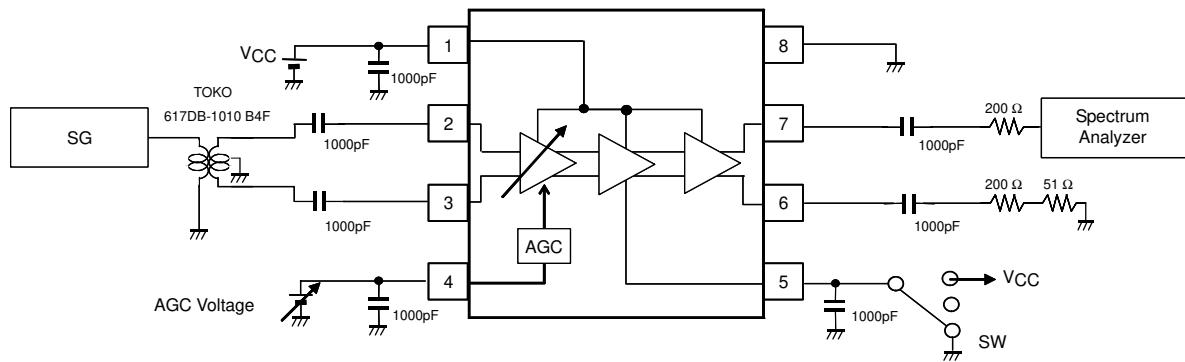


## Pin Functions

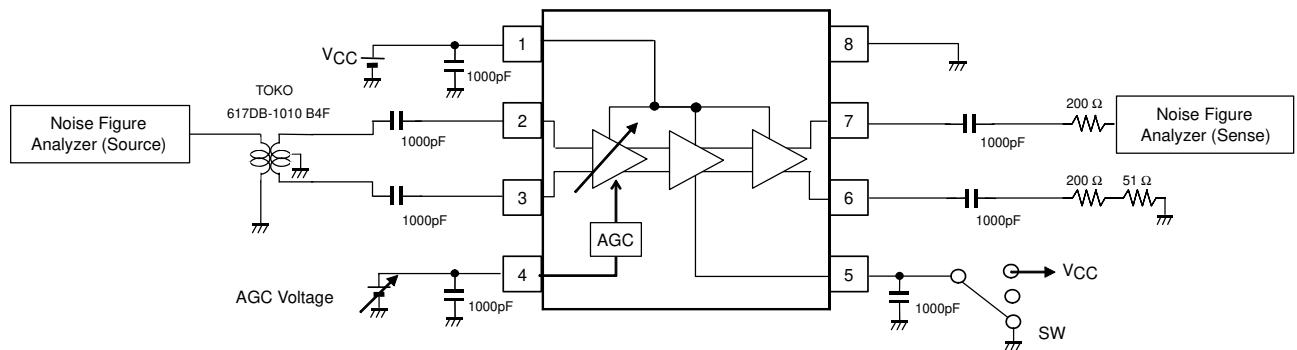
Pin Number	Pin Name	Descriptions
1	V <sub>CC</sub>	
2 3	IF Input	
4	AGC Control	
5	Gain Control Switch	
6 7	Driver Output	
8	GND	

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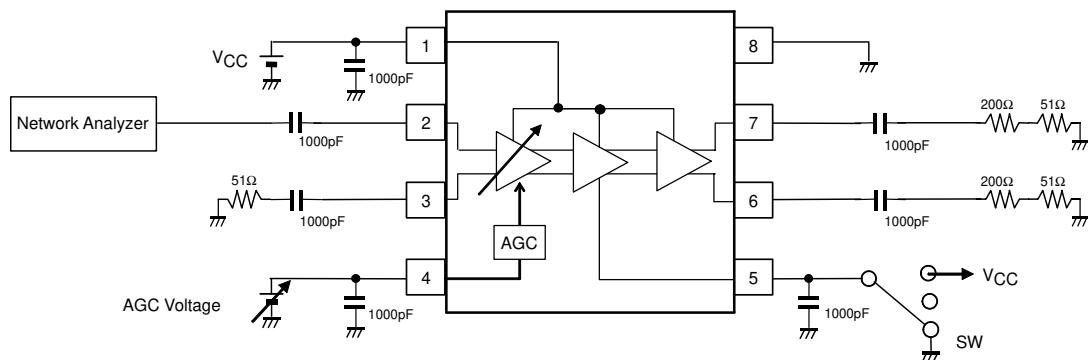
## LA7795T Gain Measurement Circuit 1



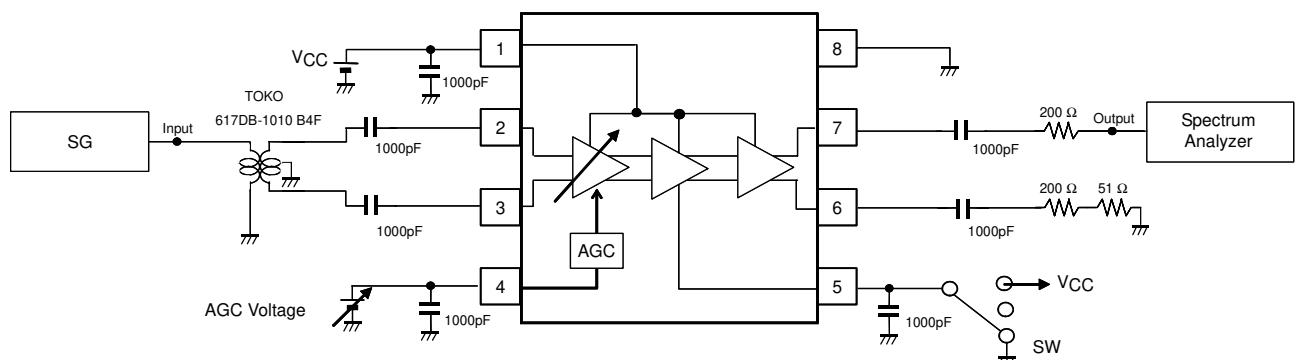
## LA7795T Noise Figure Measurement Circuit 2



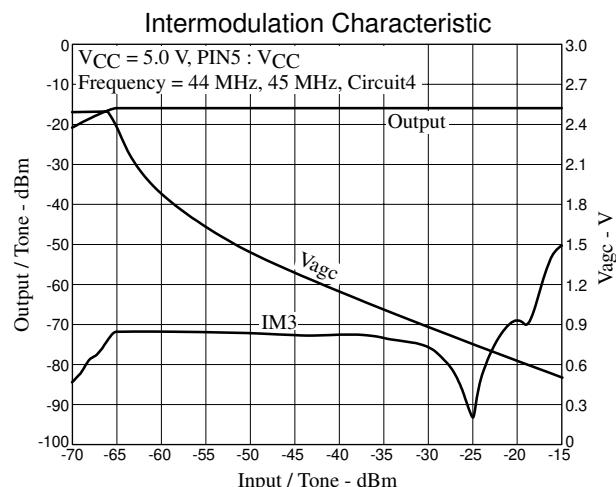
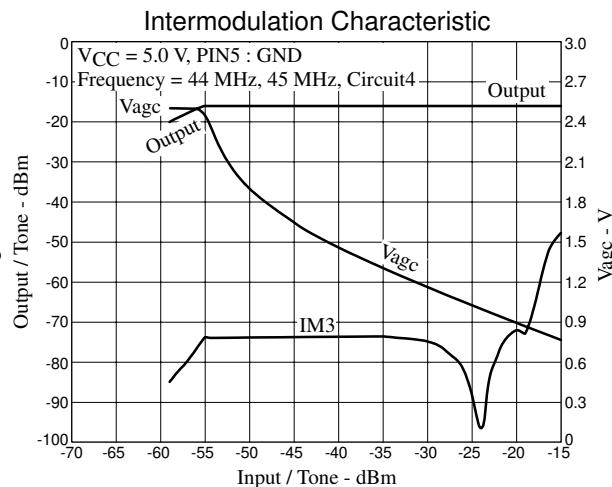
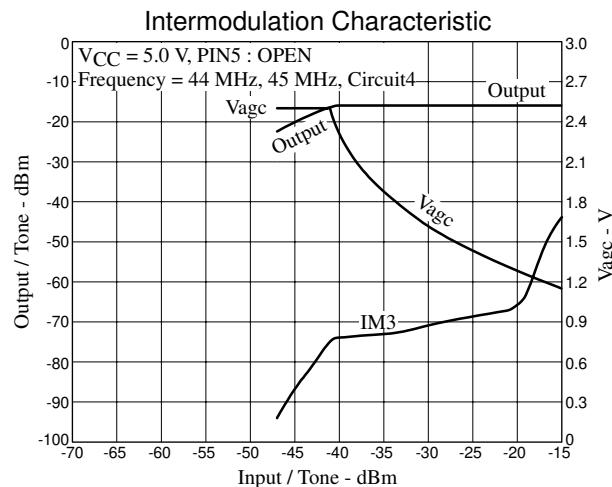
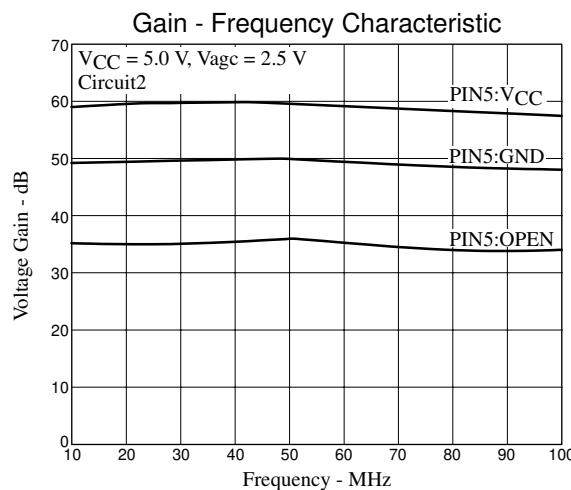
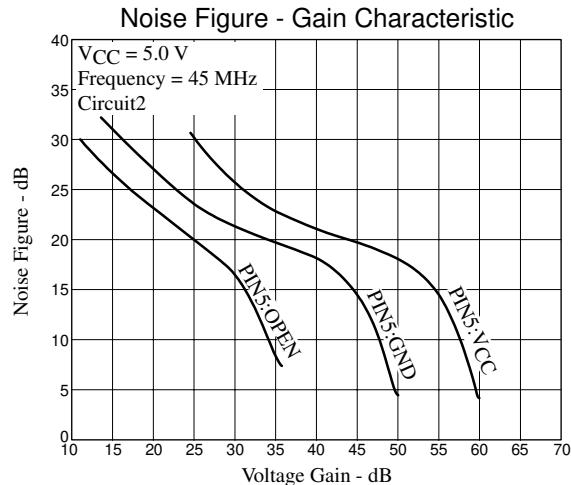
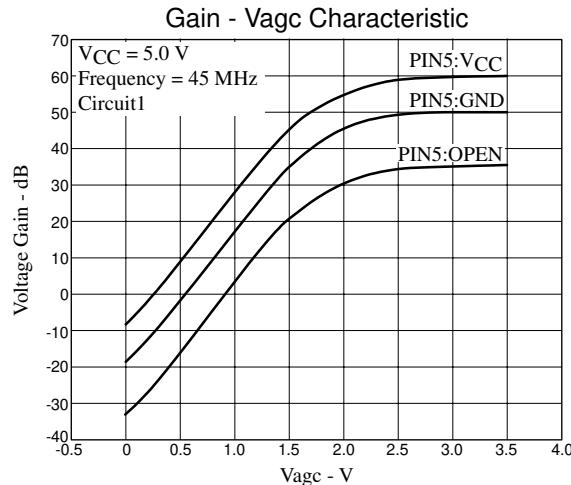
## LA7795T Input Impedance Measurement Circuit 3



## LA7795T Intermodulation Measurement Circuit 4



# LA7795T

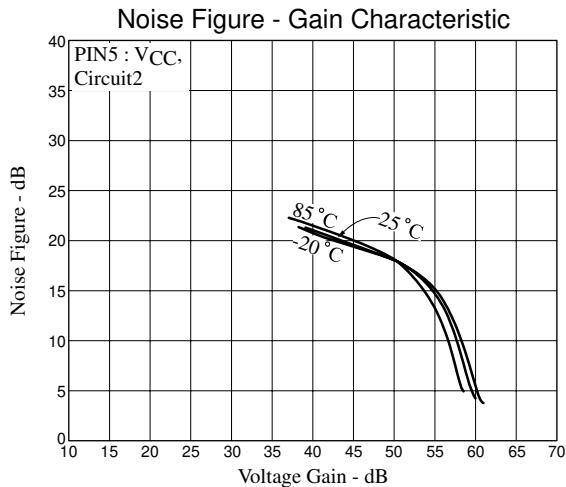
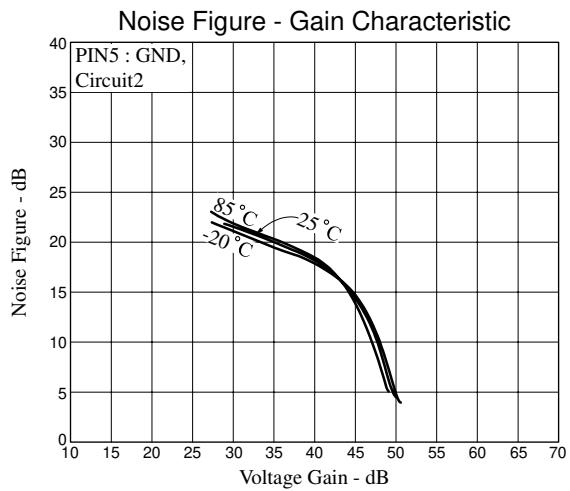
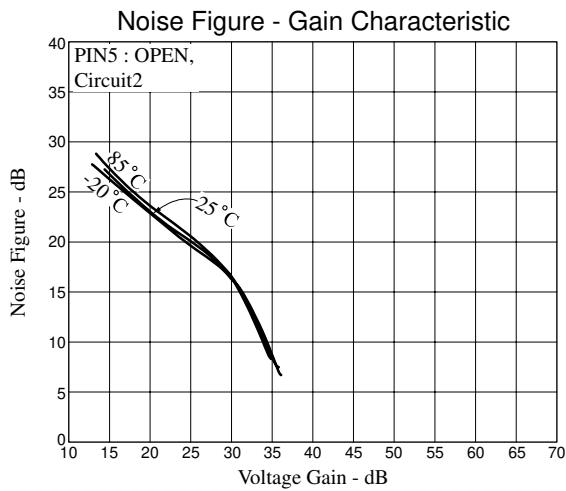
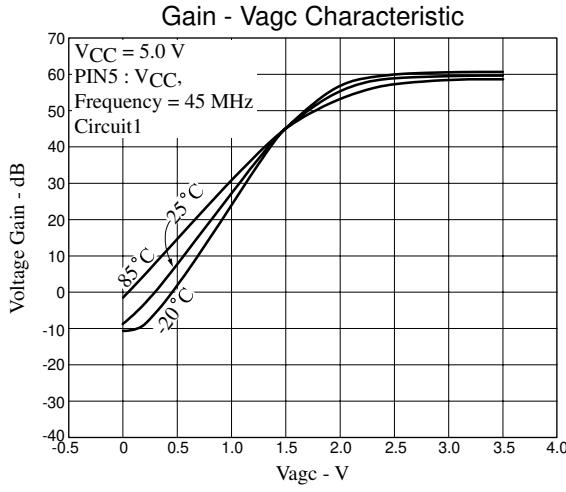
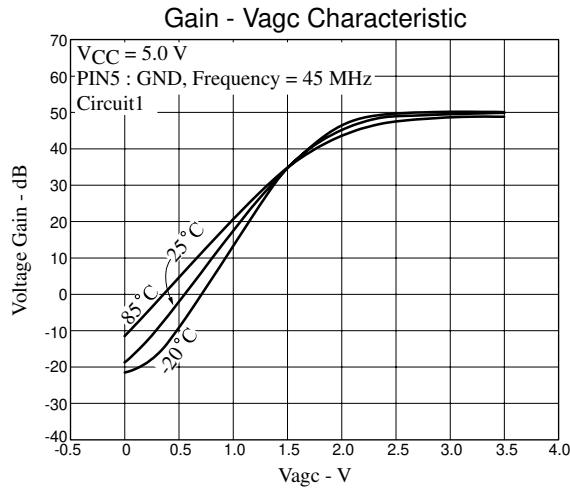
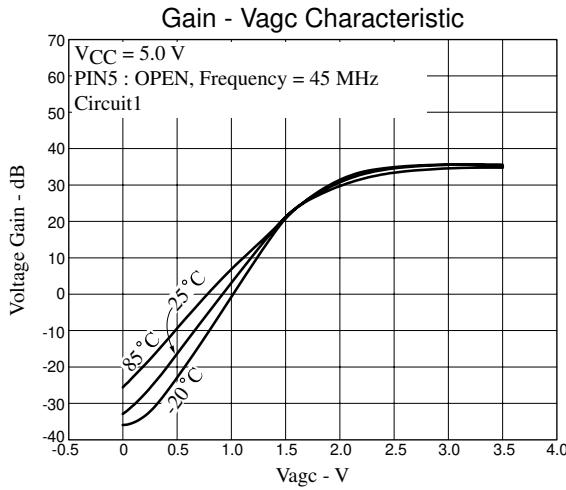


The vertical axis (Output/Tone) on this graph shows the values displayed by the spectrum analyzer for circuit 4.

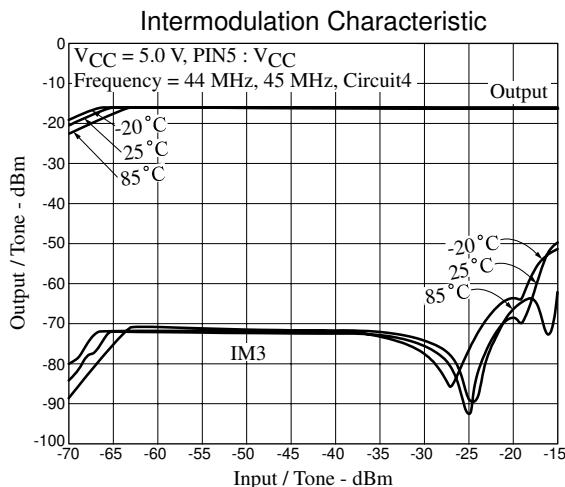
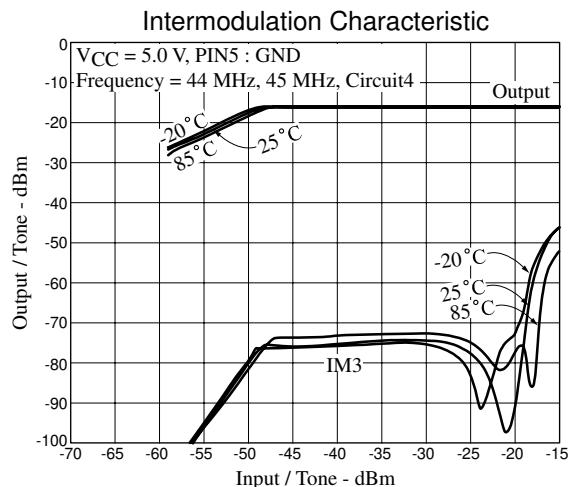
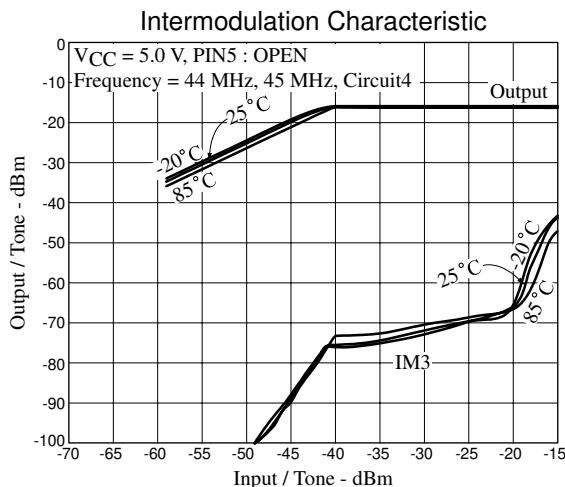
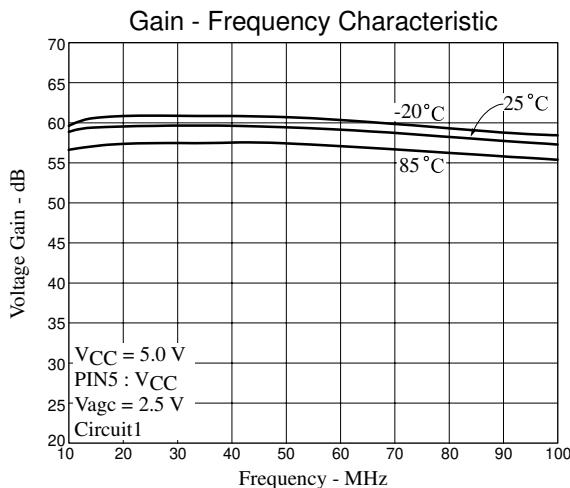
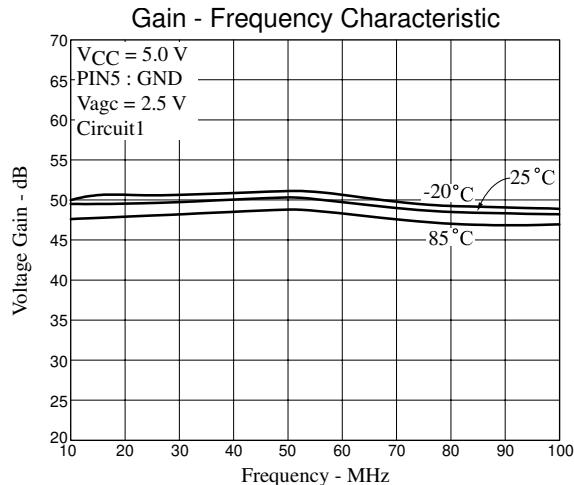
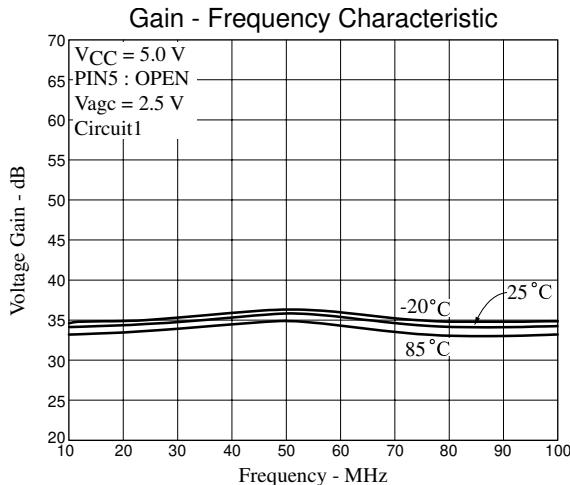
The actual output power for the corresponding pins is given by the following formula.

$$\{\text{output power [dBm]}\} = \{\text{displayed value [dBm]}\} + 10 \cdot \log (250 \Omega / 50 \Omega)$$

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The vertical axis (Output/Tone) on this graph shows the values displayed by the spectrum analyzer for circuit 4.

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